

**Amplifier, Power, 1.6W  
10.0-13.25 GHz**

**MAAP-000070-PKG003**

Rev —  
Advance Information

## Features

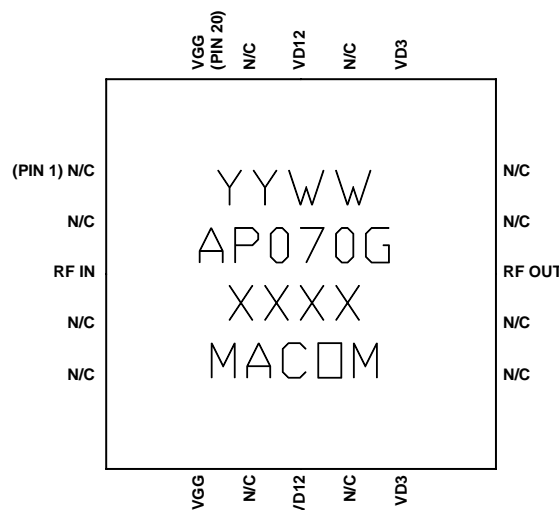
- ◆ **1.6 Watt Saturated Output Power Level**
- ◆ **Variable Drain Voltage (4-10V) Operation**
- ◆ **MSAG™ Process**

## Description

The MAAP-000070-PKG0003 is a 4-stage 1.6 W power amplifier with on-chip bias networks in a 20 lead MLP package, allowing easy assembly. This product is fully matched to 50 ohms on both the input and output. It can be used as a power amplifier stage or as a driver stage in high power applications.

Each device is 100% RF tested to ensure performance compliance. The part is fabricated using M/A-COM's GaAs Multifunction Self-Aligned Gate (MSAG) Process.

M/A-COM's MSAG™ process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors and multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



## Primary Applications

- ◆ **Point-to-Point Radio**
- ◆ **SatCom**
- ◆ **Radio Location**

## Also Available in:

Description	Die	Ceramic Package	Die Sample Board	Die Mechanical Sample	Packaged Sample Board
Part Number	MAAPGM0070-DIE	MAAPGM0070	MAAP-000070-SMB004	MAAP-000070-MCH000	MAAP-000070-SMB003 (Lead Free)

**Electrical Characteristics:  $T_B = 40^\circ\text{C}^1$ ,  $Z_0 = 50\ \Omega$ ,  $V_{DD} = 8\text{V}$ ,  $I_{DQ} = 900\text{mA}^2$ ,  $P_{in} = 7\ \text{dBm}$**

Parameter	Symbol	Typical	Units
Bandwidth	f	10.0-13.25	GHz
Output Power	$P_{OUT}$	29	dBm
1-dB Compression Point	$P_{1dB}$	31	dBm
Small Signal Gain	G	25	dB
Input VSWR	VSWR	2.0:1	
Output VSWR	VSWR	2.5:1	
Gate Current	$I_{GG}$	10	mA
Drain Current	$I_{DD}$	1400	mA

1.  $T_B$  = MMIC Base Temperature
2. Adjust  $V_{GG}$  between -2.5 and -1.2V to achieve specified  $I_{DQ}$ .

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

- **North America** Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- **Asia/Pacific** Tel: 81.44.844.8296 / Fax: 81.44.844.8298

Visit [www.macom.com](http://www.macom.com) for additional data sheets and product information.

Amplifier, Power, 1.6W  
10.0-13.25 GHz

MAAP-000070-PKG003

Rev —  
Advance Information

### Maximum Operating Conditions <sup>3</sup>

Parameter	Symbol	Absolute Maximum	Units
Input Power	$P_{IN}$	23.0	dBm
Drain Supply Voltage	$V_{DD}$	+12.0	V
Gate Supply Voltage	$V_{GG}$	-3.0	V
Quiescent Drain Current (No RF)	$I_{DQ}$	1.4	A
Quiescent DC Power Dissipated (No RF)	$P_{DISS}$	14.2	W
Junction Temperature	$T_J$	170	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

3. Operation beyond these limits may result in permanent damage to the part.

### Recommended Operating Conditions <sup>4</sup>

Characteristic	Symbol	Min	Typ	Max	Unit
Drain Voltage	$V_{DD}$	4.0	8.0	10.0	V
Gate Voltage	$V_{GG}$	-2.5	-2.0	-1.2	V
Input Power	$P_{IN}$		18.0	20.0	dBm
Junction Temperature	$T_J$			150	°C
Thermal Resistance	$\Theta_{JC}$		10.8		°C/W
MMIC Base Temperature	$T_B$			Note 4	°C

4. Operation outside of these ranges may reduce product reliability.

5. MMIC Base Temperature = 170°C —  $\Theta_{JC} * V_{DD} * I_{DQ}$

### Operating Instructions

This device is static sensitive. Please handle with care. To operate the device, follow these steps.

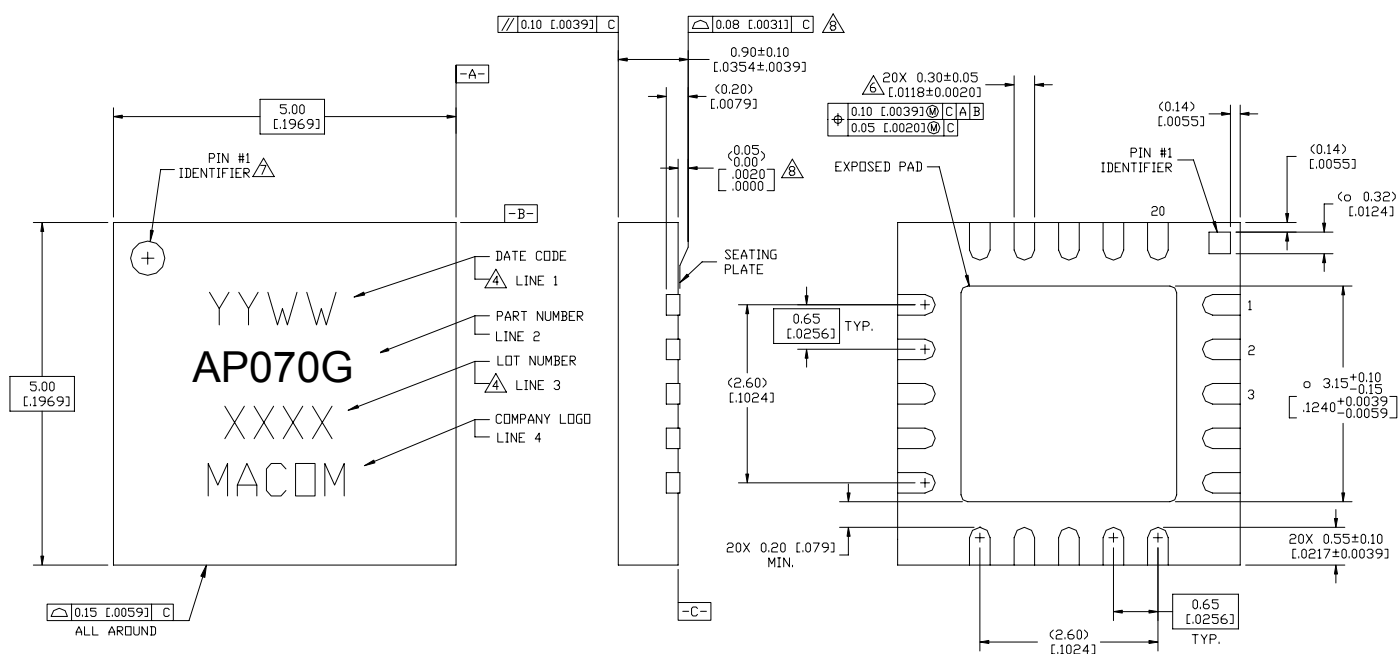
1. Apply  $V_{GG} = -2$  V,  $V_{DD} = 0$  V.
2. Ramp  $V_{DD}$  to desired voltage, typically 8.0 V.
3. Adjust  $V_{GG}$  to set  $I_{DQ}$ , (approximately @ -2 V).
4. Set RF input.
5. Power down sequence in reverse. Turn  $V_{GG}$  off last.



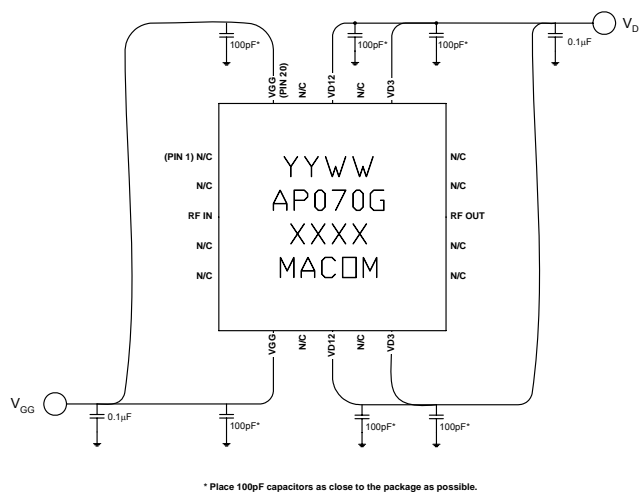
**Amplifier, Power, 1.6W  
10.0-13.25 GHz**

**MAAP-000070-PKG003**

Rev —  
Advance Information



**Figure 1. 5x5 mm 20-Lead MLP.**



\* Place 100pF capacitors as close to the package as possible.

**Figure 2. Recommended Bias Configuration.**

Note: The exposed pad centered on the package bottom must be connected to RF and dc ground for proper electrical and thermal operation.

Refer to M/A-COM Application Note **Surface Mounting Instructions for PQFN Packages #S2083\*** for assembly guidelines.

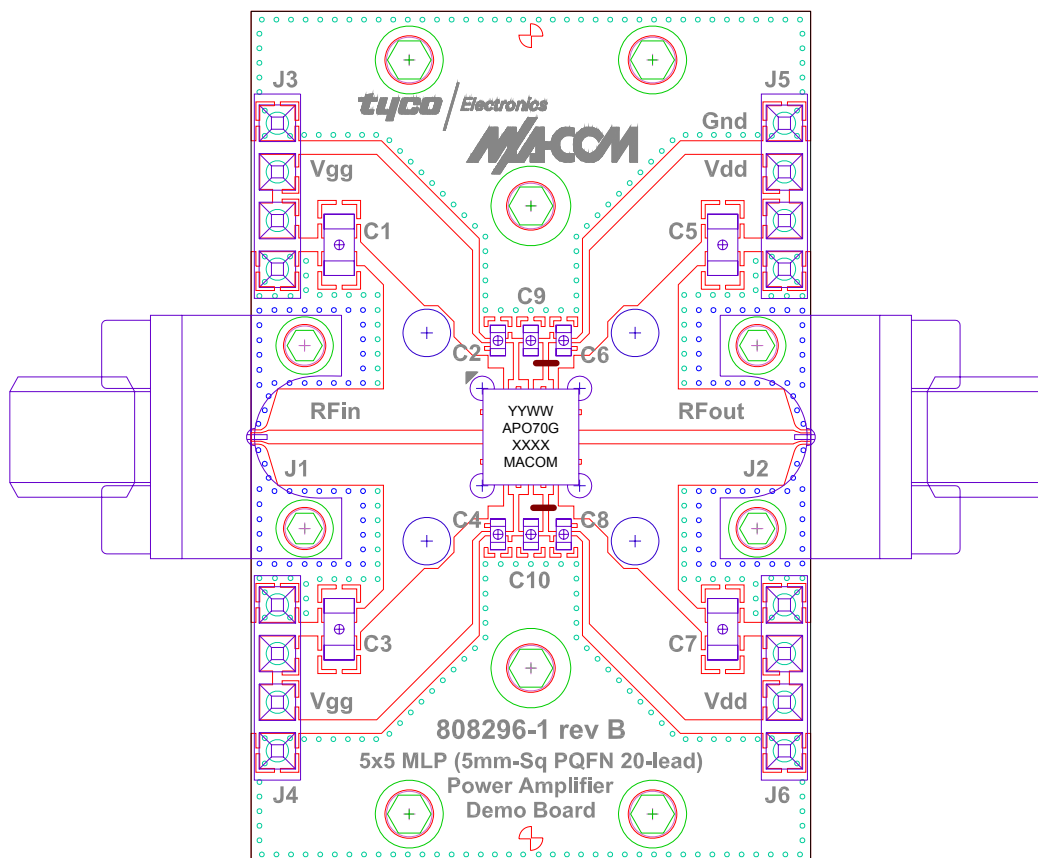
**Additional Precaution:** All parts must receive a bake-out of 125°C for 24 hours prior to any solder reflow operation.

\*Application Notes can be found by going to the Site Search Page of M/A-COM's web page (<http://www.macom.com/Application%20Notes/index.htm>) and searching for the required Application Note.

**Amplifier, Power, 1.6W  
10.0-13.25 GHz**

**MAAP-000070-PKG003**

Rev —  
Advance Information



**Figure 3. Demonstration Board PN MAAP-000070-SMB003 (available upon request).**